

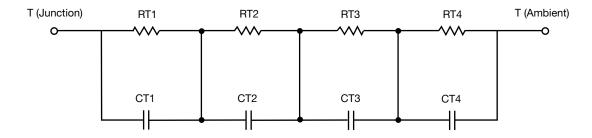
## **R-C Thermal Model Parameters**

#### **DESCRIPTION**

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

#### **R-C THERMAL MODEL FOR TANK CONFIGURATION**



THERMAL RESISTANCE (°C/W)						
Junction to	Ambient	Case	Foot			
RT1	N/A	5.3013m	N/A			
RT2	N/A	246.6575m	N/A			
RT3	N/A	60.8093m	N/A			
RT4	N/A	18.0025m	N/A			
	THERMAL CAPAC	ITANCE (Joules/°C)				
Junction to	Ambient	Case	Foot			
CT1	N/A	26.3598m	N/A			
CT2	N/A	261.5030m	N/A			
CT3	N/A	1.2413	N/A			
CT4	N/A	25.8191m	N/A			

#### Note

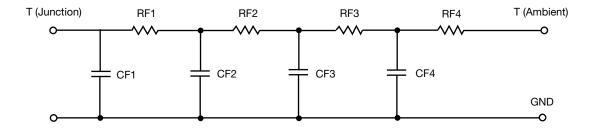
• n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

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### **R-C THERMAL MODEL FOR FILTER CONFIGURATION**



R-C VALUES FOR FILTER CONFIGURATION						
THERMAL RESISTANCE (°C/W)						
Junction to	Ambient	Case	Foot			
RF1	N/A	24.5391m	N/A			
RF2	N/A	268.4083m	N/A			
RF3	N/A	28.1563m	N/A			
RF4	N/A	9.0804m	N/A			
	THERMAL CAPAC	CITANCE (Joules/°C)				
Junction to	Ambient	Case	Foot			
CF1	N/A	13.3952m	N/A			
CF2	N/A	197.4962m	N/A			
CF3	N/A	78.3204m	N/A			
CF4	N/A	302.3423m	N/A			

#### Note

• n/a indicates not applicable





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